# **74AUP1G57**

# Low-power configurable multiple function gate Rev. 8 — 23 February 2018

**Product data sheet** 

#### **General description** 1

The 74AUP1G57 provides configurable multiple functions. The output state is determined by eight patterns of 3-bit input. The user can choose the logic functions AND, OR, NAND, NOR, XNOR, inverter, and buffer. All inputs can be connected to V<sub>CC</sub> or GND.

This device ensures a very low static and dynamic power consumption across the entire V<sub>CC</sub> range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using I<sub>OFF</sub>. The I<sub>OFF</sub> circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

The 74AUP1G57 has Schmitt trigger inputs making it capable of transforming slowly changing input signals into sharply defined, jitter-free output signals.

The inputs switch at different points for positive and negative-going signals. The difference between the positive voltage  $V_{T+}$  and the negative voltage  $V_{T-}$  is defined as the input hysteresis voltage V<sub>H</sub>.

#### **Features and benefits**

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- ESD protection:
  - HBM JESD22-A114F exceeds 5000 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM JESD22-C101E exceeds 1000 V
- Low static power consumption;  $I_{CC} = 0.9 \mu A$  (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V<sub>CC</sub>
- I<sub>OFF</sub> circuitry provides partial power-down mode operation
- · Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



# 3 Ordering information

**Table 1. Ordering information** 

Type number	Package							
	Temperature range	Name	Description	Version				
74AUP1G57GW	-40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363				
74AUP1G57GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm	SOT886				
74AUP1G57GF	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1 x 0.5 mm	SOT891				
74AUP1G57GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 x 1.0 x 0.35 mm	SOT1115				
74AUP1G57GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 x 1.0 x 0.35 mm	SOT1202				
74AUP1G57GX	-40 °C to +125 °C	X2SON6	plastic thermal extremely thin small outline package; no leads; 6 terminals; body 1 x 0.8 x 0.35 mm	SOT1255				

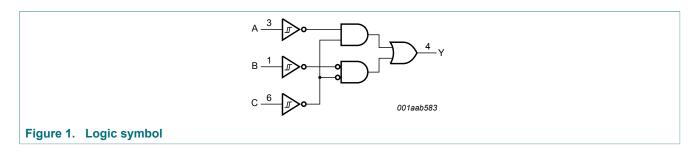
## 4 Marking

Table 2. Marking

Type number	Marking code <sup>[1]</sup>
74AUP1G57GW	aC
74AUP1G57GM	aC
74AUP1G57GF	aC
74AUP1G57GN	aC
74AUP1G57GS	aC
74AUP1G57GX	aC

<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

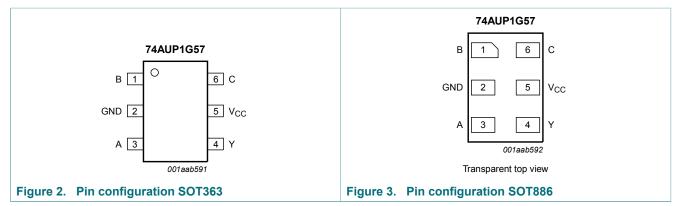
## 5 Functional diagram

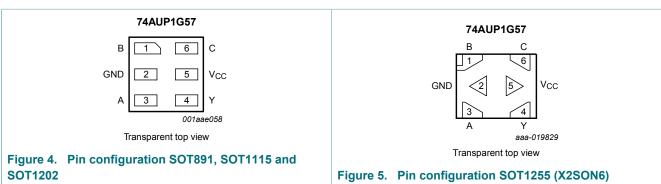


Low-power configurable multiple function gate

## 6 Pinning information

# 6.1 Pinning





## 6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
В	1	data input
GND	2	ground (0 V)
Α	3	data input
Υ	4	data output
V <sub>CC</sub>	5	supply voltage
С	6	data input

## 7 Functional description

#### Table 4. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$ 

Input			Output
С	В	A	Υ
L	L	L	Н
L	L	Н	L
L	Н	L	Н
L	Н	Н	L
Н	L	L	L
Н	L	Н	L
Н	Н	L	Н
Н	Н	Н	Н

## 7.1 Logic configurations

**Table 5. Function selection table** 

Logic function	Figure
2-input AND	see Figure 6
2-input AND with both inputs inverted	see Figure 9
2-input NAND with inverted input	see Figure 7 and Figure 8
2-input OR with inverted input	see Figure 7 and Figure 8
2-input NOR	see Figure 9
2-input NOR with both inputs inverted	see Figure 6
2-input XNOR	see Figure 10
Inverter	see Figure 11
Buffer	see Figure 12

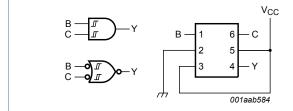


Figure 6. 2-input AND gate or 2-input NOR gate with both inputs inverted

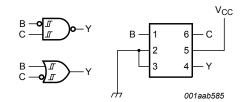


Figure 7. 2-input NAND gate with input B inverted or 2-input OR gate with inverted C input

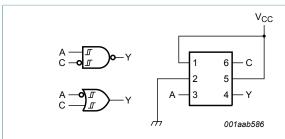


Figure 8. 2-input NAND gate with input C inverted or 2-input OR gate with inverted A input

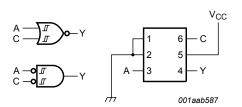


Figure 9. 2-input NOR gate or 2-input AND gate with both inputs inverted

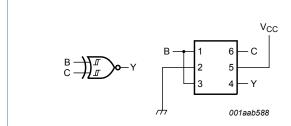


Figure 10. 2-input XNOR gate

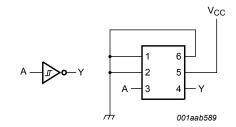


Figure 11. Inverter

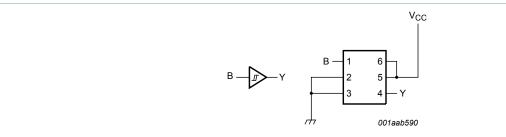


Figure 12. Buffer

## **Limiting values**

#### Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+4.6	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
Io	output current	$V_O = 0 V \text{ to } V_{CC}$	-	±20	mA
I <sub>CC</sub>	supply current		-	50	mA
I <sub>GND</sub>	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$ [2]	-	250	mW

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed. [2] For SC-88 packages: above 87.5 °C the value of Ptot derates linearly with 4.0 mW/K.

#### **Recommended operating conditions** 9

Table 7. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	$V_{CC}$	V
		Power-down mode; V <sub>CC</sub> = 0 V	0	3.6	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C

For X2SON6 and XSON6 packages: above 118 °C the value of P<sub>tot</sub> derates linearly with 7.8 mW/K.

## 10 Static characteristics

## Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 2	5 °C					
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		$I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 0.8 $V$ to 3.6 $V$	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.75 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.11	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.32	-	-	V
		$I_{O}$ = -2.3 mA; $V_{CC}$ = 2.3 V	2.05	-	-	V
		$I_{O}$ = -3.1 mA; $V_{CC}$ = 2.3 V	1.9	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.72	-	-	V
		$I_{O}$ = -4.0 mA; $V_{CC}$ = 3.0 V	2.6	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		$I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.31	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.31	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.31	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.44	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.31	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.44	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.1	μA
I <sub>OFF</sub>	power-off leakage current	$V_1$ or $V_0$ = 0 V to 3.6 V; $V_{CC}$ = 0 V	-	-	±0.2	μΑ
$\Delta I_{OFF}$	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.2	μΑ
I <sub>CC</sub>	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.5	μΑ
ΔI <sub>CC</sub>	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}$	-	-	40	μΑ
Cı	input capacitance	$V_I$ = GND or $V_{CC}$ ; $V_{CC}$ = 0 V to 3.6 V	-	1.1	-	pF
Co	output capacitance	$V_O = GND; V_{CC} = 0 V$	-	1.7	-	pF

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = -4	10 °C to +85 °C			ı		
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		$I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 0.8 $V$ to 3.6 $V$	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.7 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.03	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.30	-	-	V
		$I_{O}$ = -2.3 mA; $V_{CC}$ = 2.3 V	1.97	-	-	V
		$I_{O}$ = -3.1 mA; $V_{CC}$ = 2.3 V	1.85	-	-	V
		$I_{O}$ = -2.7 mA; $V_{CC}$ = 3.0 V	2.67	-	-	V
		$I_{O}$ = -4.0 mA; $V_{CC}$ = 3.0 V	2.55	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		$I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.37	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.35	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.33	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.45	V
		$I_{O}$ = 2.7 mA; $V_{CC}$ = 3.0 V	-	-	0.33	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.45	V
l <sub>l</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.5	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_I$ or $V_O$ = 0 V to 3.6 V; $V_{CC}$ = 0 V	-	-	±0.5	μΑ
Δl <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.6	μΑ
I <sub>CC</sub>	supply current	$V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.9	μΑ
Δl <sub>CC</sub>	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}$	-	-	50	μΑ

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		$I_{O}$ = -20 $\mu$ A; $V_{CC}$ = 0.8 $V$ to 3.6 $V$	V <sub>CC</sub> - 0.11	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.6 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	0.93	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.17	-	-	V
		$I_{O}$ = -2.3 mA; $V_{CC}$ = 2.3 V	1.77	-	-	V
		$I_{O}$ = -3.1 mA; $V_{CC}$ = 2.3 V	1.67	-	-	V
		$I_{O}$ = -2.7 mA; $V_{CC}$ = 3.0 V	2.40	-	-	V
		$I_{O}$ = -4.0 mA; $V_{CC}$ = 3.0 V	2.30	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		$I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.11	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.33 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.41	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.39	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.36	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.50	V
		$I_{O}$ = 2.7 mA; $V_{CC}$ = 3.0 V	-	-	0.36	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.50	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.75	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_I$ or $V_O$ = 0 V to 3.6 V; $V_{CC}$ = 0 V	-	-	±0.75	μA
ΔI <sub>OFF</sub>	additional power-off leakage current	$V_1 \text{ or } V_O = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.75	μΑ
I <sub>CC</sub>	supply current	$V_I$ = GND or $V_{CC}$ ; $I_O$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	1.4	μΑ
ΔI <sub>CC</sub>	additional supply current	$V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}$	-	-	75	μA

# 11 Dynamic characteristics

## **Table 9. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit, see Figure 14.

Symbol Parameter		Conditions		25 °C			-40 °C to +125 °C			
				Min	Typ <sup>[1]</sup>	Max	Min	Max (85 °C)	Max (125 °C)	
C <sub>L</sub> = 5 p	F									
t <sub>pd</sub>	propagation delay	A, B and C to Y; see Figure 13	[2]							
		V <sub>CC</sub> = 0.8 V		-	22.6	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V		2.8	6.5	12.6	2.5	13.0	13.2	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V		2.2	4.6	7.6	2.5	8.2	8.6	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V		2.1	3.9	6.2	2.0	6.8	7.2	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V		2.0	3.1	4.5	1.8	5.1	5.3	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V		1.8	2.8	3.9	1.5	4.1	4.3	ns
C <sub>L</sub> = 10	pF		,		I.			1	<u> </u>	
t <sub>pd</sub>	propagation delay	A, B and C to Y; see Figure 13	[2]							
		V <sub>CC</sub> = 0.8 V		-	26.1	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V		3.2	7.3	14.4	2.8	14.9	15.2	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V		2.6	5.2	8.7	2.8	9.3	9.8	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V		2.5	4.5	7.0	2.2	7.8	8.2	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V		2.4	3.7	5.2	2.1	5.9	6.2	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V		2.3	3.4	4.6	1.9	4.9	5.1	ns
C <sub>L</sub> = 15	pF		,			<u> </u>			1	_
t <sub>pd</sub>	propagation delay	A, B and C to Y; see Figure 13	[2]							
		V <sub>CC</sub> = 0.8 V		-	31.6	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V		3.4	8.0	15.7	3.1	16.7	17.0	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V		2.8	5.7	9.4	3.1	10.4	10.9	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V		2.6	4.9	7.7	2.5	8.7	9.2	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V		2.6	4.1	5.7	2.4	6.5	6.9	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V		2.5	3.8	5.0	2.2	5.5	5.7	ns

## Low-power configurable multiple function gate

Symbol	Parameter	Conditions		25 °C			-40 °C to +125 °C			
				Typ <sup>[1]</sup>	Max	Min	Max (85 °C)	Max (125 °C)		
C <sub>L</sub> = 30	pF									
t <sub>pd</sub>	propagation delay	A, B and C to Y; see Figure 13								
		V <sub>CC</sub> = 0.8 V	-	37.8	-	-	-	-	ns	
		V <sub>CC</sub> = 1.1 V to 1.3 V	4.6	10.4	20.9	3.9	21.8	22.3	ns	
		V <sub>CC</sub> = 1.4 V to 1.6 V	3.6	7.4	12.2	3.8	13.4	14.1	ns	
		V <sub>CC</sub> = 1.65 V to 1.95 V	3.5	6.2	9.9	3.1	11.1	11.8	ns	
		V <sub>CC</sub> = 2.3 V to 2.7 V	3.4	5.2	7.4	3.1	8.3	8.8	ns	
		V <sub>CC</sub> = 3.0 V to 3.6 V	3.2	4.9	6.6	2.8	7.0	7.4	ns	
C <sub>L</sub> = 5 p	F, 10 pF, 15 pF and	30 pF	'		1		,			
C <sub>PD</sub>	power dissipation	$f_i = 1 \text{ MHz}; V_I = \text{GND to } V_{CC}$ [3] [4]								
	capacitance	V <sub>CC</sub> = 0.8 V	-	2.6	-	-	-	-	pF	
		V <sub>CC</sub> = 1.1 V to 1.3 V	-	2.8	-	-	-	-	pF	
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	2.9	-	-	-	-	pF	
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	3.1	-	-	-	-	pF	
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	3.7	-	-	-	-	pF	
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	4.3	-	-	-	-	pF	

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

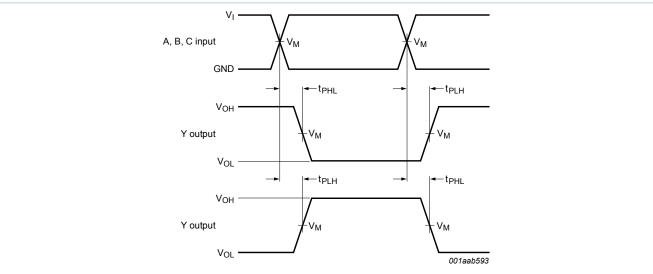
V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$  = sum of the outputs.

 <sup>[1]</sup> All typical values are measured at nominal V<sub>CC</sub>.
 [2] t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>.
 [3] All specified values are the average typical values over all stated loads.
 [4] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW).
 P<sub>D</sub> = C<sub>PD</sub> x V<sub>CC</sub><sup>2</sup> x f<sub>i</sub> x N + Σ(C<sub>L</sub> x V<sub>CC</sub><sup>2</sup> x f<sub>o</sub>) where:

## 11.1 Waveforms and test circuit



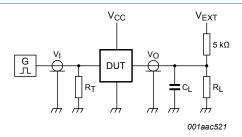
Measurement points are given in Table 10.

 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical output voltage levels that occur with the output load.

Figure 13. Input A, B and C to output Y propagation delay times

Table 10. Measurement points

Supply voltage	Output	Input			
V <sub>CC</sub>	V <sub>M</sub>	V <sub>M</sub>	VI	$t_r = t_f$	
0.8 V to 3.6 V	0.5 x V <sub>CC</sub>	0.5 x V <sub>CC</sub>	V <sub>CC</sub>	≤ 3.0 ns	



Test data is given in Table 11.

Definitions for test circuit:

R<sub>L</sub> = Load resistance.

C<sub>L</sub> = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to the output impedance  $Z_0$  of the pulse generator.

 $V_{\text{EXT}}$  = External voltage for measuring switching times.

Figure 14. Test circuit for measuring switching times

## Low-power configurable multiple function gate

Table 11. Test data

Supply voltage	Load		V <sub>EXT</sub>		
V <sub>CC</sub>	CL	R <sub>L</sub> <sup>[1]</sup>	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	$5$ k $\Omega$ or $1$ M $\Omega$	open	GND	2 x V <sub>CC</sub>

<sup>[1]</sup> For measuring enable and disable times,  $R_L$  = 5 k $\Omega$ . For measuring propagation delays, set-up and hold times, and pulse width,  $R_L$  = 1 M $\Omega$ .

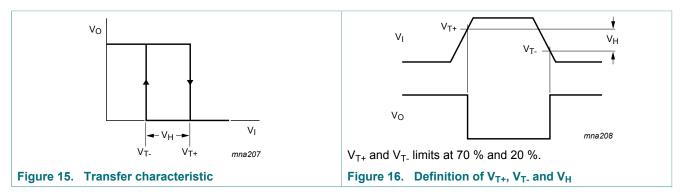
## 11.2 Transfer characteristics

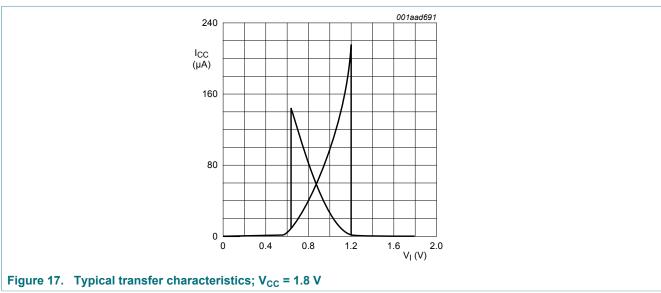
**Table 12. Transfer characteristics** 

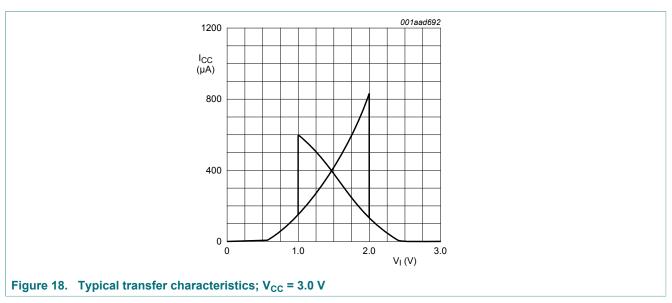
Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 14.

Symbol	Parameter	Conditions		25 °C		-40 °C to +125 °C			Unit
				Тур	Max	Min	Max (85 °C)	Max (125 °C)	
V <sub>T+</sub> positive-going threshold voltage	positive-going threshold voltage	see <u>Figure 15</u> and <u>Figure 16</u>							
		V <sub>CC</sub> = 0.8 V	0.30	-	0.60	0.30	0.60	0.62	V
		V <sub>CC</sub> = 1.1 V	0.53	-	0.90	0.53	0.90	0.92	V
		V <sub>CC</sub> = 1.4 V	0.74	-	1.11	0.74	1.11	1.13	V
		V <sub>CC</sub> = 1.65 V	0.91	-	1.29	0.91	1.29	1.31	V
		V <sub>CC</sub> = 2.3 V	1.37	-	1.77	1.37	1.77	1.80	V
		V <sub>CC</sub> = 3.0 V	1.88	-	2.29	1.88	2.29	2.32	V
V <sub>T-</sub>	negative-going threshold voltage	see <u>Figure 15</u> and <u>Figure 16</u>							
		V <sub>CC</sub> = 0.8 V	0.10	-	0.60	0.10	0.60	0.60	V
		V <sub>CC</sub> = 1.1 V	0.26	-	0.65	0.26	0.65	0.65	V
		V <sub>CC</sub> = 1.4 V	0.39	-	0.75	0.39	0.75	0.75	V
		V <sub>CC</sub> = 1.65 V	0.47	-	0.84	0.47	0.84	0.84	V
		V <sub>CC</sub> = 2.3 V	0.69	-	1.04	0.69	1.04	1.04	V
		V <sub>CC</sub> = 3.0 V	0.88	-	1.24	0.88	1.24	1.24	V
V <sub>H</sub> hystere	hysteresis voltage	(V <sub>T+</sub> - V <sub>T-</sub> ); see <u>Figure 15</u> , <u>Figure 16</u> , <u>Figure 17</u> and <u>Figure 18</u>							
		V <sub>CC</sub> = 0.8 V	0.07	-	0.50	0.07	0.50	0.50	V
		V <sub>CC</sub> = 1.1 V	0.08	-	0.46	0.08	0.46	0.46	V
		V <sub>CC</sub> = 1.4 V	0.18	-	0.56	0.18	0.56	0.56	V
		V <sub>CC</sub> = 1.65 V	0.27	-	0.66	0.27	0.66	0.66	V
		V <sub>CC</sub> = 2.3 V	0.53	-	0.92	0.53	0.92	0.92	V
		V <sub>CC</sub> = 3.0 V	0.79	-	1.31	0.79	1.31	1.31	V

## 11.3 Waveform transfer characteristics







# 12 Package outline

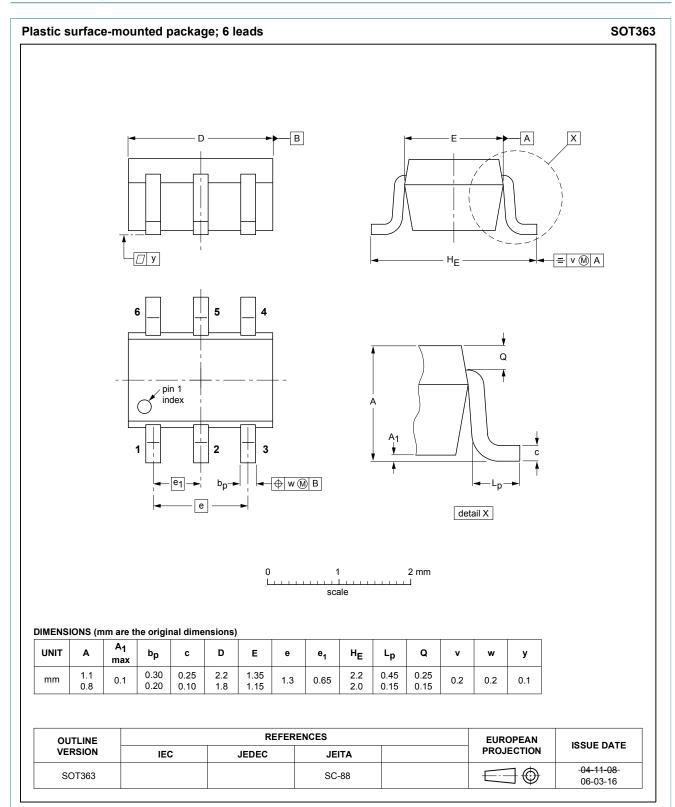


Figure 19. Package outline SOT363 (SC-88)

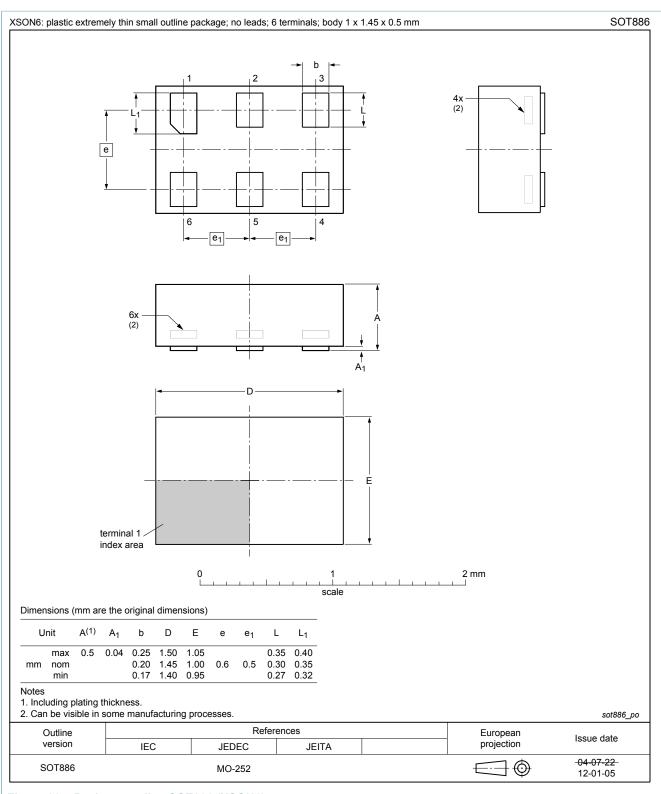


Figure 20. Package outline SOT886 (XSON6)

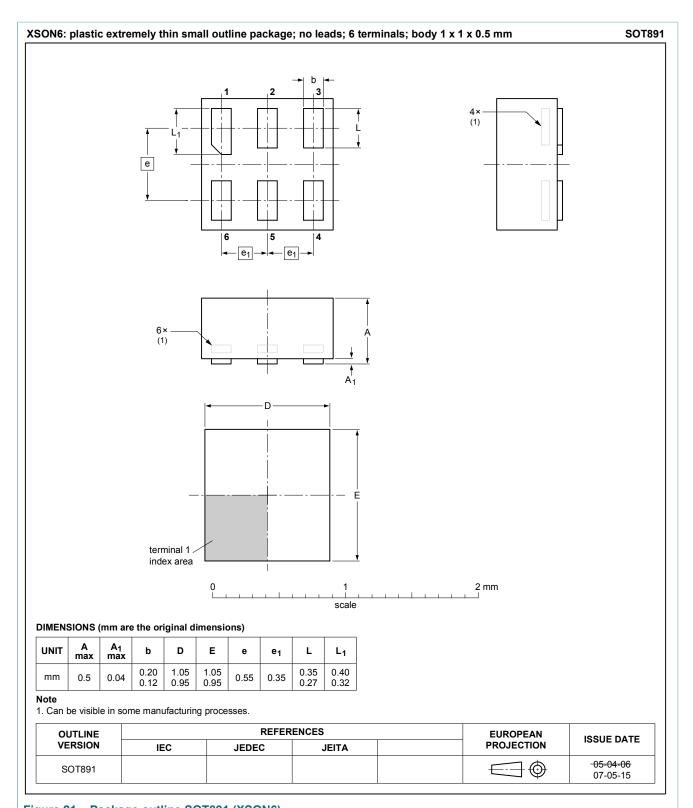


Figure 21. Package outline SOT891 (XSON6)

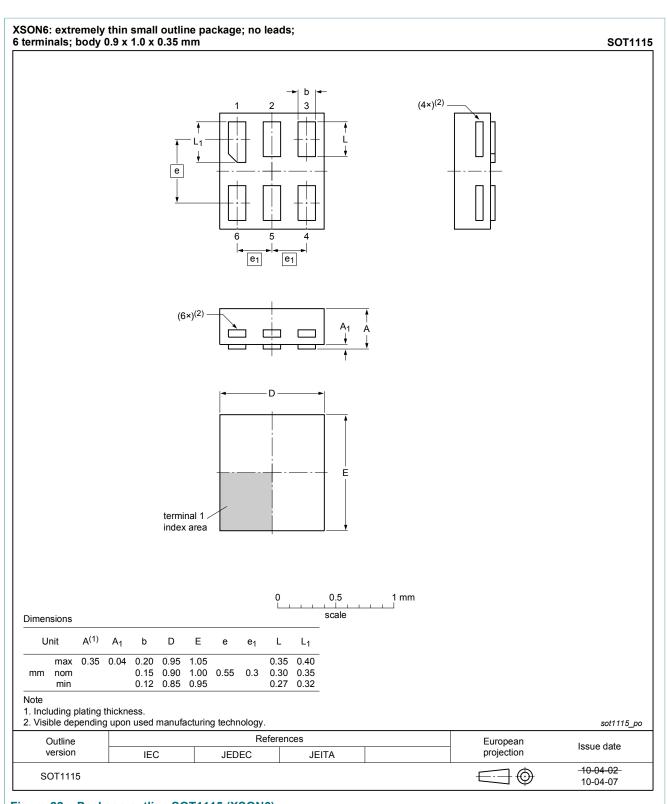


Figure 22. Package outline SOT1115 (XSON6)

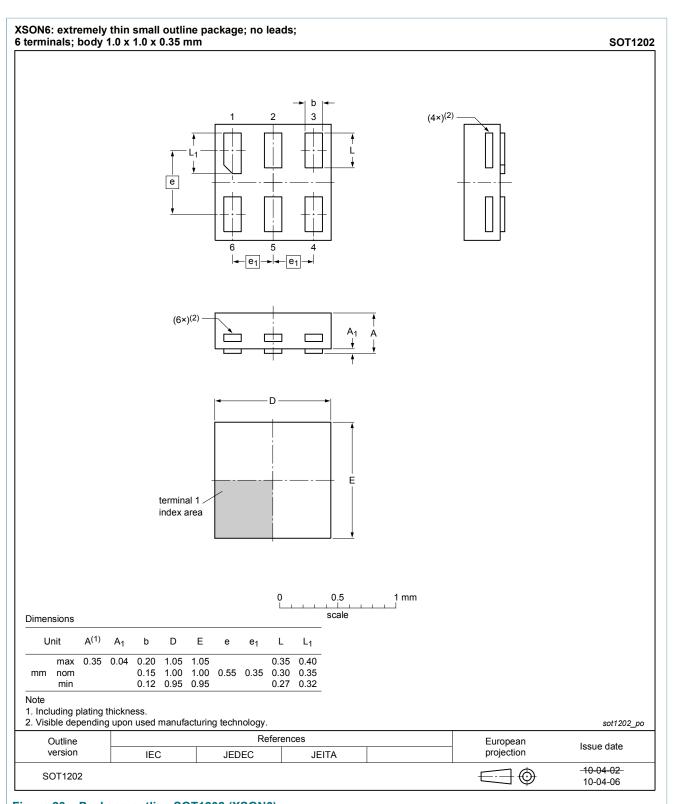


Figure 23. Package outline SOT1202 (XSON6)

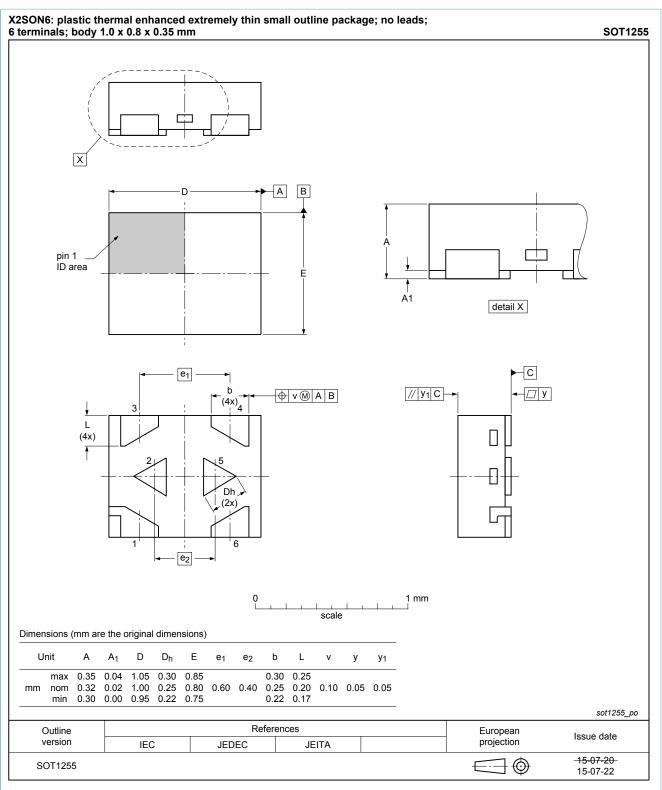


Figure 24. Package outline SOT1255 (X2SON6)

## 13 Abbreviations

#### Table 13. Abbreviations

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

# 14 Revision history

#### Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74AUP1G57 v.8	20180223	Product data sheet	-	74AUP1G57 v.7		
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>					
74AUP1G57 v.7	20150916	Product data sheet	-	74AUP1G57 v.6		
Modifications:	Added type number 74AUP1G57GX (SOT1255/X2SON6).					
74AUP1G57 v.6	20120815	Product data sheet	-	74AUP1G57 v.5		
Modifications:	<ul> <li>Package outline</li> </ul>	drawing of SOT886 (Figure 2	0) modified.			
74AUP1G57 v.5	20111125	Product data sheet	-	74AUP1G57 v.4		
74AUP1G57 v.4	20100720	Product data sheet	-	74AUP1G57 v.3		
74AUP1G57 v.3	20090622	Product data sheet	-	74AUP1G57 v.2		
74AUP1G57 v.2	20090323	Product data sheet	-	74AUP1G57 v.1		
74AUP1G57 v.1	20061123	Product data sheet	-	-		

## 15 Legal information

#### 15.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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## Low-power configurable multiple function gate

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